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Micropower 200 mA Low Dropout Tracking Regulator/Line Driver

The CS8182 is a monolithic integrated low dropout tracking regulator designed to provides an adjustable buffered output voltage that closely tracks ($\pm 10~\text{mV}$) the reference input. The output delivers up to 200 mA while being able to be configured higher, lower or equal to the reference voltages.

The device has been designed to operate over a wide range (2.8 V to 45 V) while still maintaining excellent DC characteristics. The CS8182 is protected from reverse battery, short circuit and thermal runaway conditions. The device also can withstand 45 V load dump transients and -50 V reverse polarity input voltage transients. This makes it suitable for use in automotive environments.

The V_{REF} /ENABLE lead serves two purposes. It is used to provide the input voltage as a reference for the output and it also can be pulled low to place the device in sleep mode where it nominally draws 30 μ A from the supply.

Features

- 200 mA Source Capability
- Output Tracks within ±10 mV Worst Case
- Low Dropout (0.35 V Typ. @ 200 mA)
- Low Quiescent Current
- Thermal Shutdown
- Short Circuit Protection
- Wide Operating Range
- Internally Fused Leads in SO-8 Package
- For Automotive and Other Applications Requiring Site and Change Control
- These are Pb-Free Devices

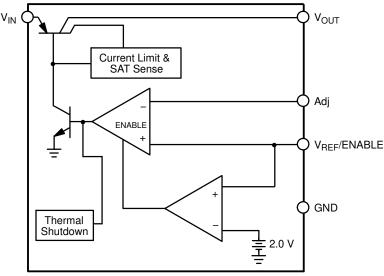
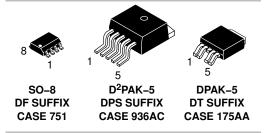


Figure 1. Block Diagram

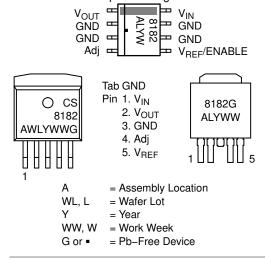


ON Semiconductor®

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PIN CONNECTIONS AND MARKING DIAGRAMS



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 9 of this data sheet.

PACKAGE PIN DESCRIPTION

	Package Lead Number				
SO-8	D ² PAK 5-PIN	DPAK 5-PIN	Lead Symbol	Function	
8	1	1	V _{IN}	Input Voltage	
1	2	2	V _{OUT}	Regulated Output	
2, 3, 6, 7	3	3	GND	Ground	
4	4	4	Adj	Adjust Lead	
5	5	5	V _{REF} /ENABLE	Reference Voltage and ENABLE Input	

MAXIMUM RATINGS

Rating	Value	Unit
Storage Temperature Range	-65 to +150	°C
Junction Temperature	+150	°C
Supply Voltage Range (Continuous)	-16 to 45	V
Peak Transient Voltage (V _{IN} = 14 V, Load Dump Transient = 31 V)	45	V
Voltage Range (Adj, V _{OUT} , V _{REF} /ENABLE)	-10 to +V _{IN}	V
Package Thermal Resistance, SO–8: Junction–to–Case, $R_{\theta JC}$ Junction–to–Air, $R_{\theta JA}$	25 80	°C/W °C/W
Package Thermal Resistance, D ² PAK Junction–to–Case, $R_{\theta JC}$ Junction–to–Air, $R_{\theta JA}$	4.0 48	°C/W °C/W
Package Thermal Resistance, DPAK Junction–to–Case, $R_{\theta JC}$ Junction–to–Air, $R_{\theta JA}$	8.0 64	°C/W °C/W
ESD Capability (Human Body Model) (Machine Model)	2.0 200	kV V
Lead Temperature Soldering: (Note 1) (SO-8 (D²PAk (DPAk	225	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. 60 second maximum above 183°C.

RECOMMENDED OPERATING RANGES

Rating	Value	Unit
Junction Temperature, T _J	-40 to+125	°C
Input Voltage, Continuous V _{IN}	3.4 to 45	V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

ELECTRICAL CHARACTERISTICS (V_{IN} = 14 V; V_{REF}/ENABLE > 2.75 V; $-40^{\circ}\text{C} < \text{T}_\text{J} < +125^{\circ}\text{C}; C_{OUT} \ge 10 \ \mu\text{F};$ 0.1 $\Omega < C_{OUT-ESR} < 1.0 \ \Omega$ @ 10 kHz, unless otherwise specified.)

Parameter	Test Conditions	Min	Тур	Max	Unit	
Regular Output						
V _{REF} – V _{OUT} V _{OUT} Tracking Error	$4.5~V \le V_{IN} \le 26~V,~100~\mu A \le I_{OUT} \le 200~mA,~Note~2$ $V_{IN} = 12~V,~I_{OUT} = 30~mA,~V_{REF} = 5.0~V,~Note~2$	-10 -5.0	-	10 5	mV mV	
Dropout Voltage (V _{IN} – V _{OUT})	I _{OUT} = 100 μA I _{OUT} = 30 mA I _{OUT} = 200 mA	- - -	100 - 350	150 500 600	mV mV mV	
Line Regulation	4.5 V ≤ V _{IN} ≤ 26 V, Note 2	-	-	10	mV	
Load Regulation	100 μA \leq I _{OUT} \leq 200 mA, Note 2	_	-	10	mV	
Adj Lead Current	Loop in Regulation	-	0.2	1.0	μΑ	
Current Limit	V_{IN} = 14 V, V_{REF} = 5.0 V, V_{OUT} = 90% of V_{REF} , Note 2	250	-	700	mA	
Quiescent Current (I _{IN} – I _{OUT})	$V_{IN} = 12 \text{ V, } I_{OUT} = 200 \text{ mA}$ $V_{IN} = 12 \text{ V, } I_{OUT} = 100 \mu\text{A}$ $V_{IN} = 12 \text{ V, } V_{REF}/\text{ENABLE} = 0 \text{ V}$	- - -	15 75 30	25 150 55	mA μA μA	
Reverse Current	V _{OUT} = 5.0 V, V _{IN} = 0 V	_	0.2	1.5	mA	
Ripple Rejection	$f = 120 \text{ Hz}, I_{OUT} = 200 \text{ mA}, 4.5 \text{ V} \le V_{IN} \le 26 \text{ V}$	60	-	_	dB	
Thermal Shutdown	GBD	150	180	210	°C	
V _{REF} /ENABLE						
Enable Voltage	-	0.80	2.00	2.75	V	
Input Bias Current	V _{REF} /ENABLE	_	0.2	1.0	μΑ	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

^{2.} V_{OUT} connected to Adj lead.

TYPICAL CHARACTERISTICS

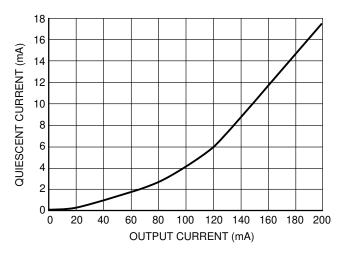


Figure 2. Quiescent Current vs. Output Current

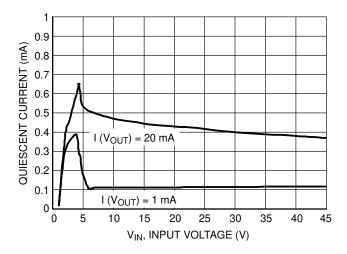


Figure 3. Quiescent Current vs. Input Voltage (Operating Mode)

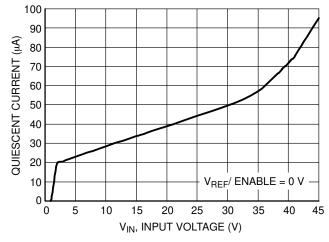


Figure 4. Quiescent Current vs. Input Voltage (Sleep Mode)

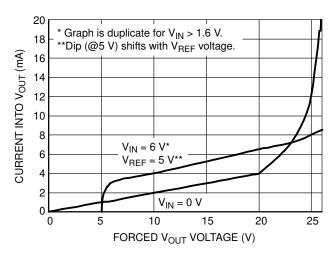


Figure 5. V_{OUT} Reverse Current

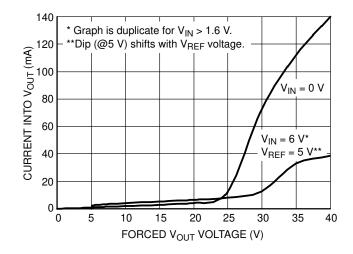


Figure 6. V_{OUT} Reverse Current

CIRCUIT DESCRIPTION

ENABLE Function

By pulling the V_{REF} /ENABLE lead below 2.0 V typically, (see Figure 10 or Figure 11), the IC is disabled and enters a sleep state where the device draws less than 55 μ A from supply. When the V_{REF} /ENABLE lead is greater than 2.75 V, V_{OUT} tracks the V_{REF} /ENABLE lead normally.

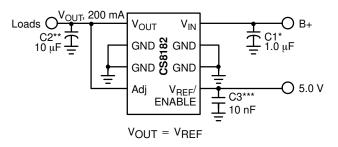


Figure 7. Tracking Regulator at the Same Voltage

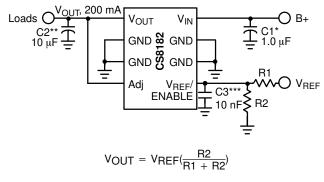


Figure 9. Tracking Regulator at Lower Voltages

Output Voltage

The output is capable of supplying 200 mA to the load while configured as a similar (Figure 7), lower (Figure 9), or higher (Figure 8) voltage as the reference lead. The Adj lead acts as the inverting terminal of the op amp and the V_{REF} lead as the non–inverting.

The device can also be configured as a high–side driver as displayed in Figure 12.

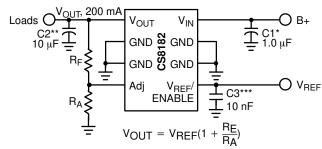


Figure 8. Tracking Regulator at Higher Voltages

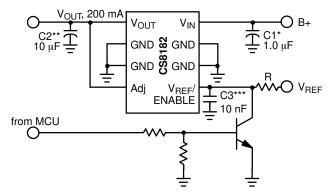


Figure 10. Tracking Regulator with ENABLE Circuit

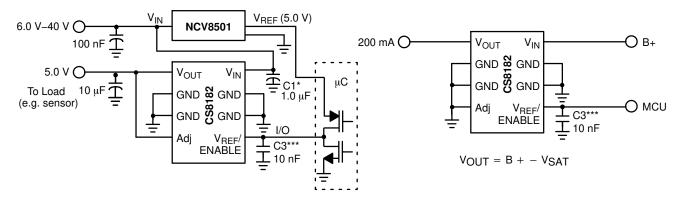


Figure 11. Alternative ENABLE Circuit

- * C1 is required if the regulator is far from the power source filter.
- ** C2 is required for stability.
- *** C3 is recommended for EMC susceptibility.

Figure 12. High-Side Driver

APPLICATION NOTES

Vout Short to Battery

The CS8182 will survive a short to battery when hooked up the conventional way as shown in Figure 13. No damage to the part will occur. The part also endures a short to battery when powered by an isolated supply at a lower voltage as in

Figure 14. In this case the CS8182 supply input voltage is set at 7 V when a short to battery (14 V typical) occurs on V_{OUT} which normally runs at 5 V. The current into the device (ammeter in Figure 14) will draw additional current as displayed in Figure 15.

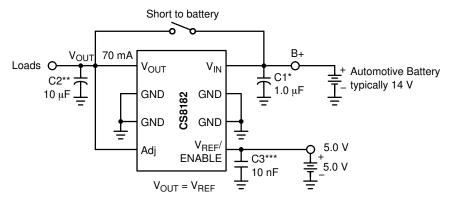


Figure 13.

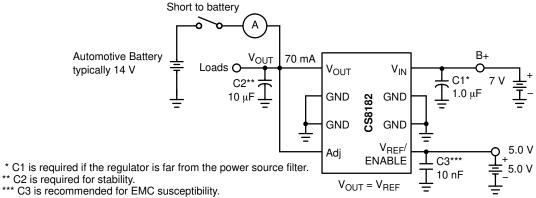
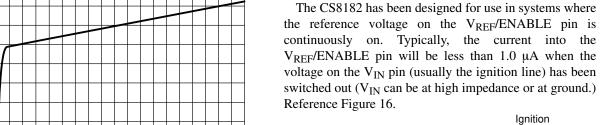


Figure 14.

Switched Application



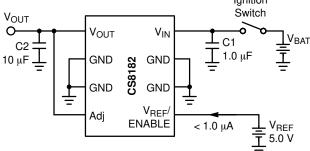


Figure 16.

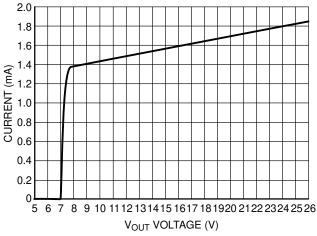


Figure 15. V_{OUT} Short to Battery

External Capacitors

The output capacitor for the CS8182 is required for stability. Without it, the regulator output will oscillate. Actual size and type may vary depending upon the application load and temperature range. Capacitor effective series resistance (ESR) is also a factor in the IC stability. Worst–case is determined at the minimum ambient temperature and maximum load expected.

The output capacitor can be increased in size to any desired value above the minimum. One possible purpose of this would be to maintain the output voltage during brief conditions of negative input transients that might be characteristic of a particular system.

The capacitor must also be rated at all ambient temperatures expected in the system. To maintain regulator stability down to -40°C, a capacitor rated at that temperature must be used.

Ceramic Capacitor Stability

The CS8182 has been verified to work with ceramic output capacitors with an additional series resistor simulating traditional ESR of tantalum capacitors; however, it has been determined the best operational performance is with a 330 m Ω series resistor (or parallel combination of three 1 Ω resistors) in conjunction with a 22 μ F output capacitor. Values outside of this are known to have limited performance with respect to stability. For more information, please contact your local ON Semiconductor sales office.

Calculating Power Dissipation in a Single Output Linear Regulator

The maximum power dissipation for a single output regulator (Figure 17) is:

$$PD(max) = \{V_{IN}(max) - V_{OUT}(min)\} I_{OUT}(max) + V_{IN}(max)I_{Q}$$
(1)

where:

V_{IN(max)} is the maximum input voltage,

V_{OUT(min)} is the minimum output voltage,

 $I_{OUT(max)}$ is the maximum output current, for the application,and

 I_Q is the quiescent current the regulator consumes at $I_{OUT(max)}. \label{eq:lower}$

Once the value of PD(max) is known, the maximum permissible value of $R_{\theta JA}$ can be calculated:

$$R_{\theta JA} = \frac{150^{\circ} C - T_A}{P_D}$$
 (2)

The value of $R_{\theta JA}$ can then be compared with those in the package section of the data sheet. Those packages with $R_{\theta JA}$'s less than the calculated value in equation 2 will keep the die temperature below 150°C.

In some cases, none of the packages will be sufficient to dissipate the heat generated by the IC, and an external heat sink will be required.

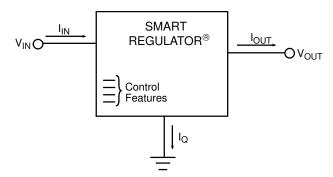


Figure 17. Single Output Regulator with Key Performance Parameters Labeled

Heatsinks

A heatsink effectively increases the surface area of the package to improve the flow of heat away from the IC and into the surrounding air.

Each material in the heat flow path between the IC and the outside environment will have a thermal resistance. Like series electrical resistances, these resistances are summed to determine the value of $R_{\theta JA}$:

$$R_{\theta JA} = R_{\theta JC} + R_{\theta CS} + R_{\theta SA}$$
 (3)

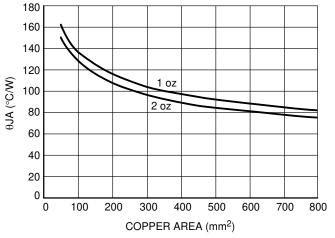
where:

 $R_{\theta JC}$ = the junction-to-case thermal resistance,

 $R_{\theta CS}$ = the case-to-heatsink thermal resistance, and

 $R_{\theta SA}$ = the heatsink-to-ambient thermal resistance.

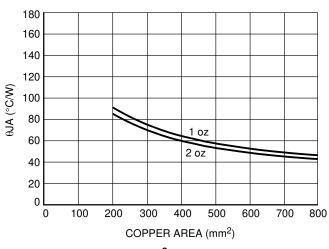
 $R_{\theta JC}$ appears in the package section of the data sheet. Like $R_{\theta JA}$, it is a function of package type. $R_{\theta CS}$ and $R_{\theta SA}$ are functions of the package type, heatsink and the interface between them. These values appear in heat sink data sheets of heatsink manufacturers.



θJA (°C/W) 1 oz 2 oz COPPER AREA (mm²)

Figure 18. 8 Lead SOIC (Fused) Thermal Resistance

Figure 19. 5 Lead DPAK Thermal Resistance



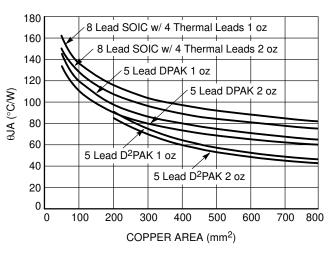


Figure 20. 5 Lead D²PAK Thermal Resistance

Figure 21. Thermal Resistance Summary

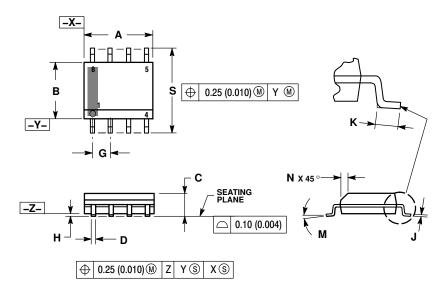
ORDERING INFORMATION

Device	Package	Shipping [†]
CS8182YDF8G	SO-8 (Pb-Free)	95 Units / Rail
CS8182YDFR8G	SO-8 (Pb-Free)	2500 / Tape & Reel
CS8182YDPS5G	D ² PAK 5-PIN (Pb-Free)	50 Units / Rail
CS8182YDPSR5G	D ² PAK 5-PIN (Pb-Free)	750 / Tape & Reel
CS8182DTG	DPAK 5L (Pb-Free)	50 Units / Rail
CS8182DTRKG	DPAK 5L (Pb-Free)	2500 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

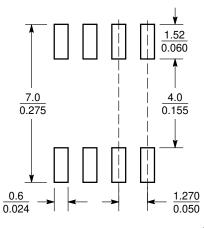
SOIC-8 **DF SUFFIX** CASE 751-07 **ISSUE AK**



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.
 3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
 5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
 6. 751–01 THRU 751–06 ARE OBSOLETE. NEW
- 751–01 THRU 751–06 ARE OBSOLETE. NEW STANDARD IS 751–07.

	MILLIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	4.80	5.00	0.189	0.197	
В	3.80	4.00	0.150	0.157	
С	1.35	1.75	0.053	0.069	
D	0.33	0.51	0.013	0.020	
G	1.27	1.27 BSC		0.050 BSC	
Н	0.10	0.25	0.004	0.010	
J	0.19	0.25	0.007	0.010	
K	0.40	1.27	0.016	0.050	
М	0 °	8 °	0 °	8 °	
N	0.25	0.50	0.010	0.020	
S	5.80	6.20	0.228	0.244	

SOLDERING FOOTPRINT*

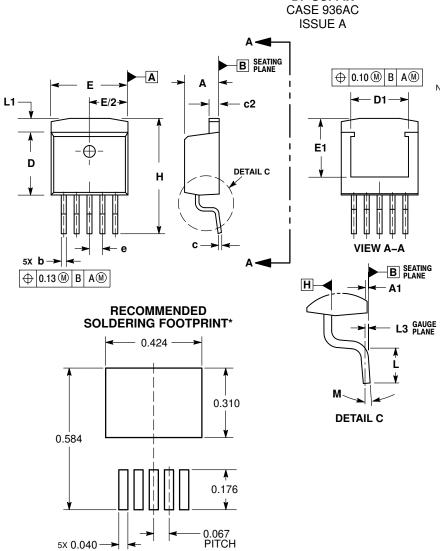


SCALE 6:1

^{*}For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

D²PAK-5 **DP SUFFIX**



- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSION: INCHES.
 3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH AND GATE PROTRUSIONS. MOLD FLASH AND GATE PROTRUSIONS NOT TO EXCEED 0.005 MAXIMUM PER SIDE. THESE DIMENSIONS TO BE MEASURED AT DATUM H.
 4. THERMAL PAD CONTOUR OPTIONAL WITHIN DIMENSIONS E, L1, D1, AND E1. DIMENSIONS D1 AND E1 ESTABLISH A MINIMUM MOUNTING SURFACE FOR THE THERMAL PAD.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.170	0.180	4.32	4.57
A1	0.000	0.010	0.00	0.25
b	0.026	0.036	0.66	0.91
С	0.017	0.026	0.43	0.66
c2	0.045	0.055	1.14	1.40
D	0.325	0.368	8.25	9.53
D1	0.250		6.35	
Е	0.380	0.420	9.65	10.67
E1	0.200		5.08	
е	0.06	7 BSC	1.70	BSC
Н	0.580	0.620	14.73	15.75
L	0.090	0.110	2.29	2.79
L1		0.066		1.68
L3	0.010 BSC		0.2	5 BSC
М	0 °	8 °	0 °	8 °

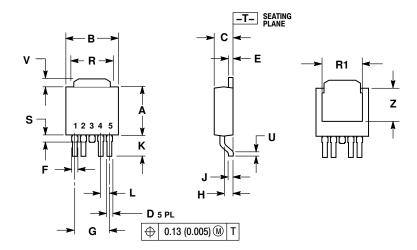
DIMENSIONS: MILLIMETERS

5X 0.040

^{*}For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

DPAK-5 DT SUFFIX CASE 175AA ISSUE B

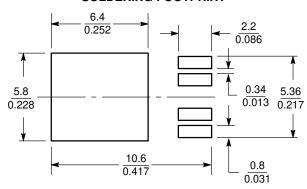


NOTES:

- 1. DIMENSIONING AND TOLERANCING
- PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.235	0.245	5.97	6.22	
В	0.250	0.265	6.35	6.73	
С	0.086	0.094	2.19	2.38	
D	0.020	0.028	0.51	0.71	
Е	0.018	0.023	0.46	0.58	
F	0.024	0.032	0.61	0.81	
G	0.180	BSC	4.56 BSC		
Н	0.034	0.040	0.87	1.01	
J	0.018	0.023	0.46	0.58	
K	0.102	0.114	2.60	2.89	
L	0.045	BSC	1.14 BSC		
R	0.170	0.190	4.32	4.83	
R1	0.185	0.210	4.70	5.33	
S	0.025	0.040	0.63	1.01	
U	0.020		0.51		
٧	0.035	0.050	0.89	1.27	
Z	0.155	0.170	3.93	4.32	

SOLDERING FOOTPRINT*



SCALE 4:1 (mm

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N. American Technical Support: 800–282–9855 Toll Free USA/Canada

Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910 Japan Customer Focus Center Phone: 81-3-5817-1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

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